

PHOTONICS Research

3D integrated photonics platform with deterministic geometry control

JÉRÔME MICHON,^{1,*} SARAH GEIGER,^{1,2} LAN LI,^{3,4}  CLAUDIA GONCALVES,⁵ HONGTAO LIN,⁶ 
KATHLEEN RICHARDSON,⁵ XINQIAO JIA,^{2,7} AND JUEJUN HU^{1,8}

¹Department of Materials Science and Engineering, Massachusetts Institute of Technology, Cambridge, Massachusetts 02139, USA

²Department of Biological Engineering, University of Delaware, Newark, Delaware 19716, USA

³Key Laboratory of 3D Micro/Nano Fabrication and Characterization of Zhejiang Province, School of Engineering, Westlake University, Hangzhou 310024, China

⁴Institute of Advanced Technology, Westlake Institute for Advanced Study, Hangzhou 310024, China

⁵College of Optics & Photonics, University of Central Florida, Orlando, Florida 32816, USA

⁶College of Information Science and Electronic Engineering, Zhejiang University, Hangzhou 310027, China

⁷e-mail: xjia@udel.edu

⁸e-mail: hujuejun@mit.edu

*Corresponding author: jmichon@mit.edu

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3D photonics promises to expand the reach of photonics by enabling the extension of traditional applications to nonplanar geometries and adding novel functionalities that cannot be attained with planar devices. Available material options and device geometries are, however, limited by current fabrication methods. In this work, we pioneer a method that allows for placement of integrated photonic device arrays at arbitrary predefined locations in 3D using a fabrication process that capitalizes on the buckling of a 2D pattern. We present theoretical and experimental validation of the deterministic buckling process, thus demonstrating implementation of the technique to realize what we believe to be the first fully packaged 3D integrated photonics platform. Application of the platform for mechanical strain sensing is further demonstrated. © 2020 Chinese Laser Press

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1. INTRODUCTION

3D integrated photonics have recently emerged as a means to provide optical systems with the same deployment flexibility as the widely successful flexible and 3D electronics. While fiber-optic-based strategies can be utilized in 3D structures, 3D integrated photonics present advantages of manufacturing scalability and tight optical confinement that allows for strong light–matter interactions as well as the possibility to readily define complex geometries without axial symmetry in high-volume production. Furthermore, the addition of integrated photonic capabilities to 3D mesostructures is poised to broaden the range of applications of such structures far beyond the cutting-edge mechanical, electrical, and optical capabilities that have been demonstrated to date [1–5].

Existing 3D fabrication methods for integrated photonics present limitations on achievable geometries with currently available materials. So-called 3D photonic multilayer devices, made by stacking 2D layers of optical components, remain inherently planar and can only interact with their environment at the surface of the device stack [5–7]. While bendable or stretchable membranes such as “e-skin” can be deformed into various

3D shapes, they remain limited to curvilinear geometries that are inherently 2D in topology [8–12]. 3D printing technologies are capable of producing almost arbitrary 3D shapes but are limited by their resolution and the lack of printable high-optical index materials required for small footprint, high-quality waveguide devices [13,14]. Buckling of 2D structures after fabrication or strategies for transference of planar structures onto a prestretched elastomeric substrate have been demonstrated as a viable way of creating many different 3D shapes [15,16], although compatibility of the technique with integrated photonic device fabrication methodologies has yet to be validated.

In this paper, we propose a new fabrication route for realizing 3D integrated photonics with deterministic device array placement. We demonstrate fabrication and packaging of devices precisely matching predefined 3D geometries using this technique. Finally, we show that such a device can be used for mechanical sensing by quantifying its stress-optical coupling response. As mechanical constraints play an important role in biological systems, as they are involved in e.g., cell migration [17,18] and differentiation [19], wound healing [20–22], and tumor progression [23], our platform yields promises

for multifunctional sensing in 3D in biological and soft materials such as tissue models.

2. DETERMINISTIC 3D FABRICATION VIA BUCKLING

Our fabrication method is illustrated in Fig. 1(a). The entire photonic device is first fabricated on top of a rigid handler substrate. It is then delaminated from the handler and deformed into a 3D structure. The exact shape of the buckled strips is controlled by the thickness profile of the strip and the relative displacement of the two ends during compression. The final structure is illustrated in Fig. 1(b), with the waveguides and optical components embedded in a polymer cladding structure. The polymer is shaped into strips joining two planar edge platforms with input/output light coupling ports for the devices. For 3D sensing applications, the design allows arbitrary spatial locations to be accessed by strategically placing waveguide-coupled components (e.g., resonator sensors) on the strips. The in-plane x - y spatial coordinates of a sensing spot are given by the resonator position along the strip, whereas the out-of-plane z -coordinate is defined by the buckle height.

This fabrication process offers three key advantages. First, it leverages mature planar processing technologies that allow for highly reliable fabrication of optical components. Second, it is readily scalable to a large number of sensing channels, simply by changing the dimensions of the device (strip width, strip spacing, device overall width, etc.) without compromising the quality and throughput of fabrication. Third, it enables construction of 3D architectures by controlled, deterministic mechanical deformation—much like pop-up books, which come in a planar form and are then deformed into the desired 3D objects.

For this fabrication method to be deterministic, we need to be able to control the final shape of the buckles such that optical components can be placed at the positions of interest. The buckling of a strip (typically called a “beam” in mechanics) has been solved in a number of specific cases [24]. Our case corresponds to the buckling of a beam with “fixed ends” in which

the position and tangent of the ends of the beam are kept constant. The profile of a beam with uniform cross-section buckled under these conditions is given by [25]

$$\begin{cases} x(\phi) = \frac{1}{k} [2E(\phi, p) - F(\phi, p)] \\ h(\phi) = \frac{2p}{k} (1 - \cos \phi) \end{cases}, \quad \text{for } 0 \leq \phi \leq 2\pi, \quad (1)$$

where E (resp. F) is the incomplete elliptic integral of the first (resp. second) kind, and p and k are constants determined using the boundary conditions on the initial length of the buckle and its final span (Appendix B).

However, in this example, the span is the same for all the buckles on a device, and all of them end up with the same shape. In order to probe the full 3D space, we need to be able to give different shapes to adjacent buckles. To that end, we modulate the cross-section of the strips by varying their thickness to create new buckling profiles. The thickness is simply controlled by the number and pattern of top polymer cladding layers on the strips. By applying an additional layer on some areas of the strips but not others, the cross-section and thus the moment of the inertia of the beam vary along its length. The buckled strip shape in this case can also be solved analytically, and the solution is presented in Appendix B.

This added degree of freedom allows for many more buckle geometries. We show in the next section that fabricated devices with beams made of two segments of different thicknesses agree well with the theoretically predicted shapes. Any more complicated cases, with three or more segments of two or more thicknesses, can be solved and fabricated in a similar way.

3. FABRICATION AND PACKAGING

As mentioned previously, our approach for the fabrication of our 3D device was to first fabricate a planar device using well-established 2D fabrication techniques and then transform it into the target 3D geometry. The fabrication route is presented in Fig. 2. An important feature of this route is that the core material of the waveguides is deposited and processed directly on its polymer cladding. We chose a chalcogenide glass of the composition $\text{Ge}_{23}\text{Sb}_7\text{S}_{70}$ (GSS, with a refractive index of 2.22 at 1550 nm), as it possesses properties important for our target application of a sensing platform notably for biological materials; further, it is transparent in the near-infrared, has been shown to be nontoxic and resistant to oxidation, and has previously been used to fabricate low-loss devices with a diverse range of applications including flexible photonics [26–29]. More broadly, this fabrication route could be applied to any material amenable to direct deposition on a noncrystalline substrate, such as other glasses. SU-8 was used for the polymeric cladding, as it meets all the requirements for the encapsulation material, i.e., it has good chemical resistance notably to hydrofluoric acid (HF), which is used in a key step of our process, as detailed below, it is optically transparent at 1550 nm, it is known to be biocompatible, it is easy to process via photolithography, and it is available in a wide range of viscosity allowing for deposition of many different thicknesses (from hundreds of nanometers to hundreds of microns) via spin-coating.

Particular care is needed to release the device from its handler substrate [step (v) of Fig. 2] while preserving the integrity of the device. A distinguishing feature of our device lies in its

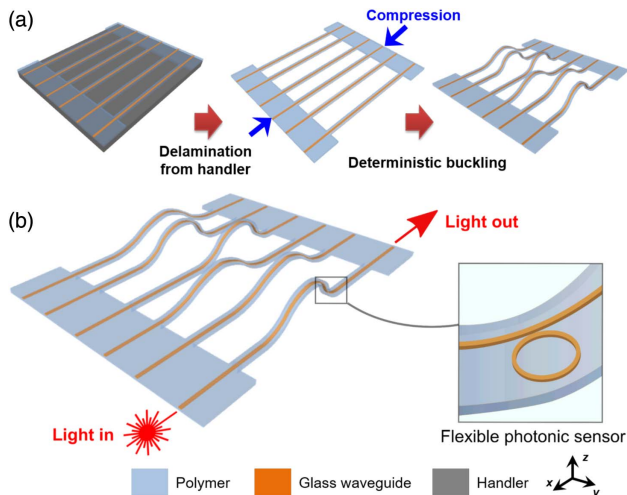


Fig. 1. (a) Schematic of the proposed 3D fabrication process. (b) Schematic of the 3D device layout.

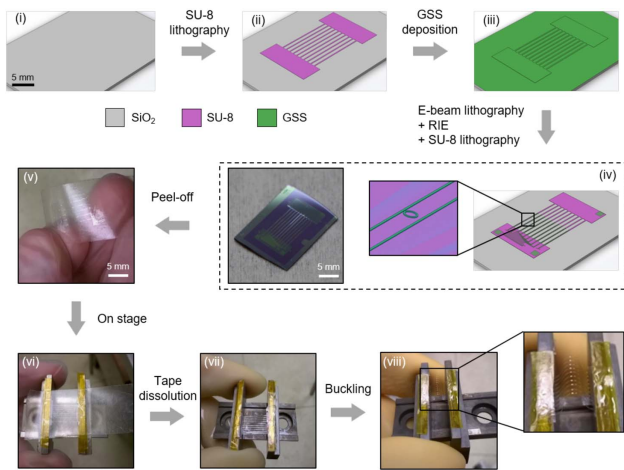


Fig. 2. Overall fabrication process flow of the 3D integrated photonics devices.

patterned structure versus other demonstrations of flexible integrated photonics based on an intact continuous film spanning the entire substrate area [30,31]. Here, the perforated membrane structure is mechanically vulnerable in a freestanding state; therefore, we developed a release process using water-soluble tape as a sacrificial supporting substrate [8] before transferring the sample to the precision motion stage for buckling. After transfer, the device lays flat on the stage. It is buckled by bringing the two ends closer together by a controlled distance [step (viii) of Fig. 2] and takes on its final 3D geometry [Fig. 3(b)]. Further details about the device and process flow can be found in Appendix A.

We validated the deterministic nature of the buckling process by comparing the predicted buckle geometries to experimentally obtained shapes. Different buckle shapes were obtained on a single device by varying the thickness of the top cladding along the strips [Fig. 3(a)], thereby modifying their cross-section and moment of inertia, eventually resulting in different buckle profiles [Fig. 3(b)]. For each buckle, characterized by its ratio of thin cladding length to thick cladding length, Fig. 3(c) shows good agreement between the experimental shape, extracted from a sideview picture of the device, and the theoretical shape predicted by Eqs. (B6) and (B7). The accuracy of the curves, limited by the resolution of the sideview pictures used to extract the experimental shapes, is estimated to be 100 μm .

Finally, to provide an easy-to-use, rugged, and reliable platform that readily interfaces with applications involving 3D photonics, the buckled devices were integrated with an optical fiber array (FA) [Fig. 4(a)]. After permanent bonding of the FA to the device using a UV-curable epoxy, optical alignment setup is no longer required to operate the device, and the devices can be remotely probed through the fiber cable connection. This is a critical advantage for many biological and biomechanical sensing applications, where the sensors often need to be deployed in a controlled environment (e.g., inside an incubator or a reactor). FAs also represent a scalable coupling scheme, allowing (time-)multiplexed measurement of many photonic devices. By combining the packaged devices with spectrally

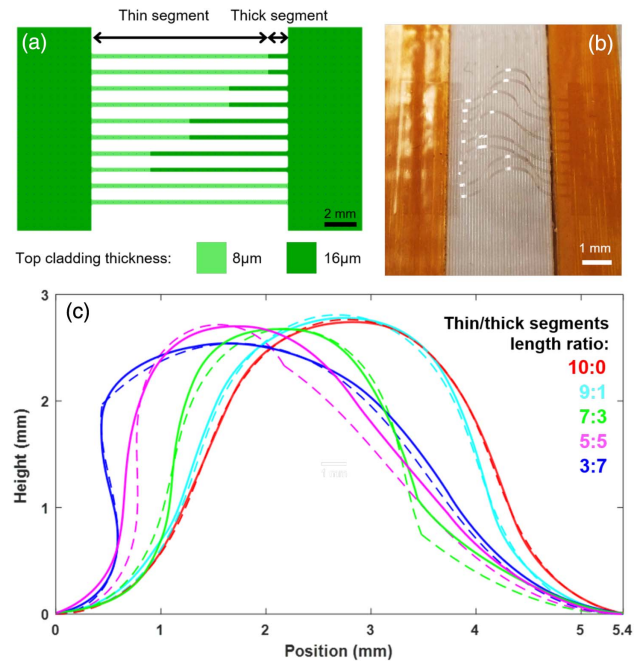


Fig. 3. (a) Thickness map of the top cladding, showing the different thin/thick segments length ratios across the buckles. In practice, different thicknesses are realized by depositing a different number of cladding layers. (b) Picture of a corresponding sample fabricated using the mask. Two of the 10 buckles are missing after breaking during peel-off. (c) Comparison of the fabricated buckle shapes (full lines) with the theoretical predictions (dashed lines).

and spatially multiplexed resonators [32], the measurement scheme can be applied to monitoring a 3D distributed sensor array containing a large number of individual sensing elements. We further demonstrated that the fiber-packaged 3D sensor array can be embedded inside a soft, biologically derived material. Figure 4(c) illustrates the process to integrate the

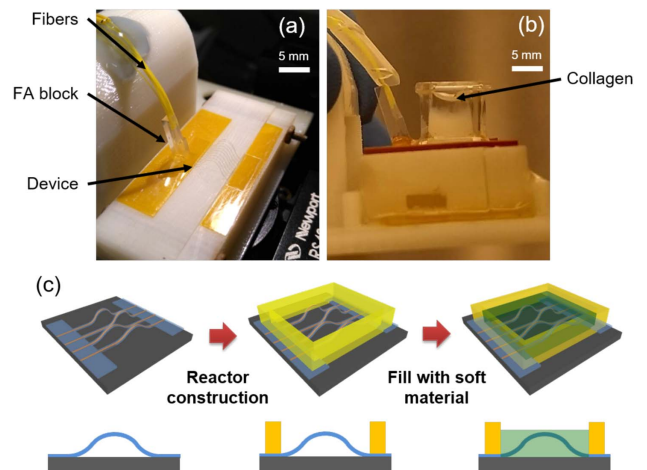


Fig. 4. (a) Buckled device with bonded 16-channel fiber array. On the left, a stress-relieving structure is used to increase the robustness of the packaged device. (b) Packaged device integrated in collagen. (c) Schematic integration process flow of the 3D sensor with a material of interest.

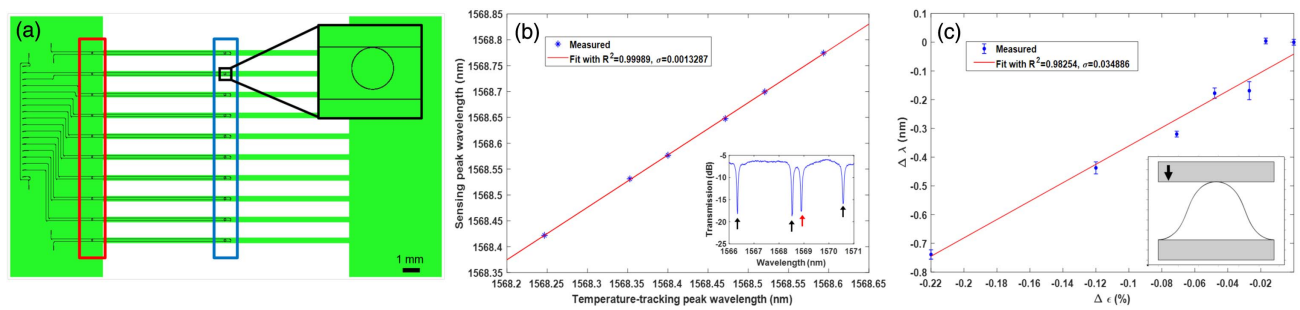


Fig. 5. (a) 2D layout of the photonic device (purple) overlaid on top of the base SU-8 pattern (green). The temperature-tracking rings are boxed in red; the sensing rings are boxed in blue. (b) Resonant wavelength of the sensing resonator as a function of the peak of the temperature-tracking resonator, without any stress applied to the device. The error bars on the wavelength readings (both vertically and horizontally) are 1 pm (too small to be seen). Inset: transmission spectrum of a device over several free-spectral ranges (FSRs), with black (resp. red) arrows denoting temperature-tracking (resp. sensing) peaks, identified through the different FSRs of the two resonators. (c) Measured resonance shift as a function of local strain at the resonators. The linear fit equation is $\Delta\lambda = 3.2 \cdot \Delta\epsilon - 0.04$ nm. Inset: COMSOL model of the system, with a buckle being deformed by a moving block.

sensor with a cell-laden collagen hydrogel, and Fig. 4(b) shows a photo of the embedded device. The approach enables *in situ*, read-time monitoring of various physical and chemical parameters in a 3D tissue model [33].

4. MECHANICAL SENSING

As its fabrication relies on planar processing, our platform can leverage all the functionalities available in the toolbox of standard integrated photonics. Optical resonators have notably been used in a wide spectrum of physical and chemical-sensing applications such as label-free protein sensing [34,35], small molecule spectroscopy [36], ultrasound detection [37], or pH and humidity monitoring [38]. Our platform therefore enables multifunctional sensing and mapping in the 3D space. A promising application of the platform is 3D mechanical sensing in tissue models. Measuring stress or strain in soft tissues is critical to the understanding of processes such as cell migration and differentiation, yet current methods either do not provide 3D information [39,40], are limited in their spatial extent [41,42], or require complex post-processing [43,44]. Therefore, here we further demonstrate the use of our platform for mechanical sensing. Optical measurements enable strain, or equivalently stress, monitoring through strain-optical coupling in resonator devices [30,45,46]. It has been shown that resonant cavity optical sensors can detect extremely small strains below 0.01% when capitalizing on high-quality resonances [30].

To achieve the target high sensitivity, the stress-induced resonant peak shift must be quantified and isolated from other interfering effects, which also result in resonance drift, in particular temperature-dependent wavelength shift (TDWS), due to the thermal-optic effect and thermal expansion of the resonator materials. The TDWS in our resonator devices was measured to be 72 pm/°C [47]. The thermally induced resonance drift is thus much larger than our resonant wavelength measurement accuracy (below 1 pm [48]) even with small temperature fluctuations. We account for the TDWS by placing a second, “temperature-tracking” resonator along each bus waveguide in the flat edge platform of the device that does not

undergo deformation [boxed in red in Fig. 5(a)]. This second resonator only responds to temperature changes in the environment. Assuming that the temperature is uniform in the space between the two resonators, measuring the TDWS of the temperature-tracking resonator allows us to calculate the TDWS of the sensing resonator (Appendix C), which is then subtracted from the sensing resonator’s measured overall wavelength shift, thereby isolating the stress-induced wavelength shift. To validate this approach, both sets of resonators were measured without any mechanical constraint applied. As shown in Fig. 5(b), the linear relationship expected from Eq. (C2) is indeed observed between the resonant wavelengths of the sensing resonator and of the temperature-tracking resonator. This method therefore enables accurate correction for noise caused by temperature fluctuations.

We then quantified the strain response of our sensors by mechanically deforming the individual strips [inset of Fig. 5(c)]. The measurement protocols are described in Appendix D. The measured resonance shift $\Delta\lambda$ is plotted against the local strain at the resonator [Fig. 5(c)], showing a linear dependence as expected for small deformations [30] with a slope of 3.2 nm/%. This value applies to all resonators with a similar geometry and a similar set of materials. In that respect, it is notably independent of the exact buckle shape and of the position of the resonator with respect to the neutral axis, as both of these contributions are accounted for in the value of the strain at the resonator’s location. The data further indicate strain measurement accuracy down to 0.01%, suggesting that the embedded photonic sensor platform can be used for sensitive 3D strain mapping in soft materials (with modulus down to 300 Pa). Based on these performances, we are now exploring the use of this device for health monitoring of 3D tissue models by detecting stiffness gradients, e.g., in cardiac graft tissues whose modulus ranges from 240 Pa for developing or damaged tissues to 1200 Pa for healthy developed tissues [49].

5. CONCLUSION

In this paper, we present a new method for the fabrication and packaging of 3D-integrated photonics with deterministic

geometry control. Our fabrication approach benefits from the performances of mature planar processing techniques; offers a controlled, deterministic means to position photonic components in 3D; and is readily scalable to a large volume of devices with unique geometries. Combining this robust manufacturing strategy with the diverse sensing capabilities offered by integrated photonics will enable a host of applications requiring the complexity of 3D. Notably, the demonstrated approach will significantly benefit applications where monitoring complex physical/chemical parameter distributions and fluxes is mandatory, e.g., in directional electromagnetic wave sensors, flow monitoring in microfluidics, nondestructive structural health monitoring (SHM) in soft materials, as well as synthetic process control in tissue engineering and additive manufacturing. In biological materials, it can also be used to selectively deliver and collect light at/from precise 3D locations to enable different *in situ* light-based diagnosis and stimulation. Overall, the 3D integrated photonic architecture is well poised to become a multifunctional 3D sensing and light delivery platform.

APPENDIX A

A.1. Device Description

Our device consists of a 2 μm thick bottom SU-8 layer, a 450 nm thick GSS layer, and an 8 μm thick top SU-8 layer (a second 8 μm thick top layer is used for thickness modulation). Waveguides are 1 μm wide; further, ring resonators have radii of 30 to 45 μm and a coupling gap of 600 nm. Loaded quality factors of $\approx 30,000$ were obtained. Light is coupled into the waveguides using a 250 μm pitched 16-channel FA of single-mode fibers (SQS Vlaknova Optika) bonded to the device's grating couplers with UV-curable epoxy (Masterbond). The insertion loss per connection is ≈ 10 dB. While not the focus of the present study, the insertion loss can be further reduced with optimized grating coupler designs.

A.2. Planar Fabrication

Si wafers coated with 300 nm thermal oxide (University Wafer) were used as substrates. To create the bottom cladding layer, SU-8 2002 (Microchem) was spin-coated, soft baked, patterned using photolithography (MA-4, Süss), hard baked, and developed with propylene glycol monomethyl ether acetate (PGMEA), according to the resist datasheet [50]. Because SU-8 films are prone to stresses [51,52], the more so the thicker they get; we used a temperature ramp for all baking steps, with a hold at 60°C before and after each bake at 95°C. GSS was then deposited onto the entire sample by thermal evaporation. Patterning of the optical components was done using electron-beam lithography followed by dry etching. Prior to electron-beam resist spin-coating, the sample underwent 1 min of oxygen plasma (100 W, 100 mTorr) to enhance adhesion of the resist, especially on top of the relatively narrow (200 μm wide) buckles, where the step profile would cause poor coverage due to edge effects. 200 nm thick SU-8 2000.2 (Microchem) was used as the electron-beam resist. During the exposure, we used a height map of the sample to correct for the error in automatic focusing due to the sample surface lying 2 μm above the surface of the substrate, which the laser-based height sensor detects. The SU-8 pattern was then transferred onto the GSS

by fluorine-based reactive ion etching (CHF_3/Ar gases at 15/35 sccm, 5 mTorr, 300 W ICP power, 60 W high-frequency power) on an inductively coupled plasma system (Oxford Instruments). SU-8 2005 was then spin-coated, soft baked, exposed, and developed with PGMEA, to create the top cladding layer.

A.3. Buckling Process

The final planar sample on its substrate was dipped in 12.5% hydrofluoric acid (HF) for about 5 min to undercut the oxide layer and release the device, until it can be visually seen to start lifting off. Water-soluble tape (3M) was then applied onto the sample. Using water-soluble tape alone led to cracks in the device after peel-off because of the low rigidity of the polyvinyl alcohol backing of the tape. We therefore also applied Kapton tape on top of the water-soluble tape to provide structural rigidity during the peeling process. Once on tape and peeled-off from the substrate, the device was placed onto the stage in its flat configuration, with both ends of the stage prepared with double-sided Kapton tape. The entire stage was then dipped in 5% hydrochloric acid (HCl) for a few hours to dilute the tape away. After rinsing in IPA, the flat device was buckled by bringing the two ends of the stage closer together by a controlled distance.

APPENDIX B: ANALYTICAL THEORY FOR PREDICTING THE SHAPE OF BUCKLES WITH NON-UNIFORM CROSS-SECTIONS

Here, we show that, given parameters under control such as the buckle's total length and its span, we can predict the shape of the buckle. The assumptions made throughout the derivations are as follows.

- The material of the beam is homogeneous and isotropic. Previous work in our group has shown that the presence of the glass could be neglected [8,30].
- The compressive load on the beam is axial only.
- The beam is free from initial stress.
- The weight of the beam (and any other lateral load) is neglected.
- The stress never exceeds the yield strain.

The following notations are also used (see Fig. 6 for geometrical notations).

- s : arc length along the buckle.
- L_{tot} : total length of the beam.
- L : length of the beam along the x direction after buckling.
- E : Young's modulus of the beam material.
- I : moment of inertia of the beam (for a given cross-section). In particular, for a beam with rectangular cross-section

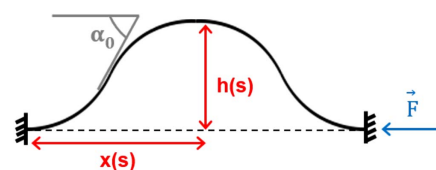


Fig. 6. Schematic sideview of a uniform cross-section buckle.

of width w and thickness t , its moment of inertia with respect to its neutral axis is $I = wb^3/3$.

– \vec{F} : load applied at the end of the beam

B.1. Uniform Cross-Section Beam Buckling

Using a large-deformation approach, the curvature is given by $d\alpha/ds$, with α the angle of deflection of the beam at each position. The differential equation governing the behavior of the beam is thus [25]

$$EI \frac{d^2\alpha}{ds^2} + \|\vec{F}\| \frac{dh}{ds} = 0. \quad (B1)$$

The value of $\|\vec{F}\|$ is unknown but will be determined later on. The profile of the buckle is then given by

$$\begin{cases} x(\phi) = \frac{1}{k}[2E(\phi, p) - F(\phi, p)] \\ h(\phi) = \frac{2p}{k}[1 - \cos(\phi)] \end{cases}, \quad \text{for } 0 \leq \phi \leq 2\pi, \quad (B2)$$

where $k^2 = \vec{F}/EI$, $p = \sin(\alpha_0/2)$ with α_0 the angle of deflection at the inflection point, and $E(\phi, p)$ and $F(\phi, p)$ are the incomplete elliptic integrals of the second and first kind, respectively. The boundary conditions used to obtain these expressions are

$$\begin{cases} h(0) = h(L) = 0 \\ h'(0) = h'(L) = 0 \end{cases}. \quad (B3)$$

The values of k and p_0 are found by considering two additional conditions: the total length L_{tot} of the device is conserved upon buckling, and the position $x(2\pi) = L$ of the right edge of the buckle is known. The total length of the buckle can be calculated as

$$L_{\text{tot}} = \int_0^{2\pi} \sqrt{x'(\phi)^2 + h'(\phi)^2} d\phi = \frac{4K(p)}{k}, \quad (B4)$$

where $K(p)$ is the complete elliptic integral of the first kind. The conditions on k and p_0 are, therefore,

$$\begin{cases} L = \frac{1}{k}[2E(2\pi, p) - F(2\pi, p)] \\ L_{\text{tot}} = \frac{4K(p)}{k} \end{cases}. \quad (B5)$$

Because elliptic integrals have no analytical expression, this system needs to be solved numerically.

B.2. Piecewise Uniform Cross-Section

Here, we consider the case of a beam made of two segments of different thicknesses. This treatment can easily be extended to three or more segments. The two segments are described by their moment of inertia, I_1 and I_2 , and their length, ℓ_1 and $\ell_2 = L_{\text{tot}} - \ell_1$. Solving Eq. (B1) for each segment yields two profiles of the form of Eq. (B2), for $0 \leq \phi \leq \Phi$ and $\Phi \leq \phi \leq 2\pi$, with Φ the (unknown yet) parameter giving the junction's position. We can write the horizontal position of the beam as

Its vertical position is

$$h(\phi) = \begin{cases} \frac{2p_1}{k_1}[1 - \cos(\phi)], & \text{for } 0 \leq \phi \leq \Phi \\ \frac{2p_1}{k_1}[1 - \cos(\Phi)] + \frac{2p_2}{k_2}[\cos(\Phi) - \cos(\phi)], & \text{for } \Phi \leq \phi \leq 2\pi \end{cases}. \quad (B7)$$

In both cases, we used the continuity at Φ .

The five equations needed to solve the five-parameter system (p_1, k_1, p_2, k_2, Φ) are given by the length of each segment, the boundary conditions at each end of the buckle, and the relation between k_1 and k_2 due to the force balance at the junction:

$$\begin{cases} \ell_1 = \frac{1}{k_1}F(\Phi, p_1) \\ \ell_2 = \frac{1}{k_2}[4K(p_2) - F(\Phi, p_2)] \\ x(2\pi) = L = \frac{1}{k_1}[2E(\Phi, p_1) - F(\Phi, p_1)] + \frac{1}{k_2}\{2[4E(p_2) - E(\Phi, p_2)] - [4K(p_2) - F(\Phi, p_2)]\} \\ h(2\pi) = 0 = \frac{2p_1}{k_1}[1 - \cos(\Phi)] + \frac{2p_2}{k_2}[\cos(\Phi) - 1] \\ \frac{k_1}{k_2} = \frac{\ell_2}{\ell_1} = \left(\frac{t_2}{t_1}\right)^3 \end{cases}. \quad (B8)$$

This system is then solved numerically.

APPENDIX C: TEMPERATURE-DEPENDENT WAVELENGTH SHIFT CORRECTION

The equation giving the temperature-dependent wavelength shift (TDWS) is [53]

$$\begin{aligned} \Delta\lambda_{\text{TDWS}} &= \alpha \frac{n_{\text{eff}}}{n_g} \lambda \Delta T + \frac{1}{n_g} \frac{\partial n_{\text{eff}}}{\partial T} \lambda \Delta T \\ &= \frac{\alpha n_{\text{eff}} + \sigma}{n_g} \lambda \Delta T = \beta \Delta T, \end{aligned} \quad (C1)$$

with T the temperature, λ the wavelength, α the thermal expansion coefficient, $\sigma = \partial n_{\text{eff}}/\partial T$, and $\beta = (\alpha n_{\text{eff}} + \sigma)/n_g$. Over a small range of temperature, we can neglect the dependence of the coupling coefficient β on temperature (through the wavelength, the effective index n_{eff} , and the group index n_g), leading to a linear relationship between TDWS and temperature. This equation can be applied to both sensing and temperature-tracking resonators [Fig. 5(a)], with different values for β , as the local geometry varies between the temperature-tracking resonator on the flat edge platform and the sensing resonator in the bent buckle. The two equations can then be combined to yield a linear relation linking the TDWS of the two resonators:

$$\Delta\lambda_{\text{TDWS, sensing}} = \frac{\beta_{\text{sensing}}}{\beta_{\text{T-tracking}}} \Delta\lambda_{\text{TDWS, T-tracking}}. \quad (C2)$$

$$x(\phi) = \begin{cases} \frac{1}{k_1}[2E(\phi, p_1) - F(\phi, p_1)], & \text{for } 0 \leq \phi \leq \Phi \\ \frac{1}{k_1}[2E(\Phi, p_1) - F(\Phi, p_1)] + \frac{1}{k_2}[2E(\phi, p_2) - E(\Phi, p_2)] - [F(\phi, p_2) - F(\Phi, p_2)], & \text{for } \Phi \leq \phi \leq 2\pi \end{cases}. \quad (B6)$$

APPENDIX D: STRAIN SENSING EXPERIMENT PROTOCOLS

We use external force to controllably deform the strips and quantify the strain-optical coupling behavior of our sensors. Specifically, the buckled strips are subjected to linear displacement of a rigid boundary (practically speaking, a block of stiff material). The experimental setup was used to acquire optical data, while finite element models were used to calculate the local strains.

In order to obtain repeatable and precise deformation, we used a piezoelectric actuator (TRA25CC, Newport) to control the vertical position of the block. The initial position was chosen such that the block would barely not touch the top of the buckle. It was then lowered in steps of 0.1 or 0.2 mm. After each block movement, an optical spectrum was acquired. The block was lowered down to 1.3 mm below its original position and then brought back up in the same increments, and several such rounds of lowering and raising were performed. The acquired spectra were analyzed to extract the peak shift of the resonators. The experiment was performed in an open laboratory without ambient temperature control. Therefore, the measured peak shift included both deformation-induced and temperature-induced contributions. The spectra acquired at the initial position, when no deformation is applied to the buckle, were thus used to calibrate the relationship between the temperature-dependent wavelength shifts of the temperature-tracking resonator and the pressure-tracking resonator. This relationship was then applied to the other spectra to calculate the temperature-induced peak drift, subtract it from the total measured peak shift, and thereby isolate the deformation-induced resonance change.

The configuration used, with the buckle constrained between the stage and an upper block, is commonly referred to as “the constrained elastica,” i.e., a beam under buckling constrained in the vertical direction. Its treatment has been the subject of a number of numerical and analytical studies [54–57]. Yet no analytical solution was found in a general case. We therefore implement numerical simulations to study this problem. We used the finite element modeling (FEM) software COMSOL to simulate the behavior of the system under the applied constraints. Given the symmetries of the problem, with the block moving only vertically and the buckle standing in a plane, a 2D model can be used. The results of the simulations include the displacement field and final curvature of the buckle. We then compared the final curvature to the curvature in the initial state to calculate the change in curvature along the buckle due to the deformation. Finally, knowing the position of the sensor along the buckle, and using the relationship between curvature and strain, we calculated the change in stress as a function of the magnitude of the deformation (in this case, the height change of the upper block).

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